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# FFSP3065A

## Silicon Carbide Schottky Diode

### 650 V, 30 A

### Features

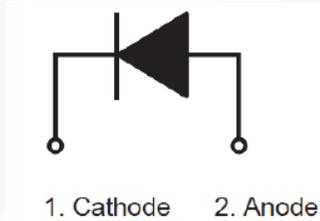
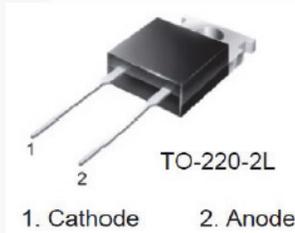
- Max Junction Temperature 175 °C
- Avalanche Rated 180 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery

### Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

### Description

SiC Schottky Diode has no switching loss, provides improved system efficiency against Si diodes by utilizing new semiconductor material - Silicon Carbide, enables higher operating frequency, and helps increasing power density and reduction of system size/cost. Its high reliability ensures robust operation during surge or over-voltage conditions



### Absolute Maximum Ratings $T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	FFSP3065A	Unit	
$V_{RRM}$	Peak Repetitive Reverse Voltage	650	V	
$E_{AS}$	Single Pulse Avalanche Energy (Note 1)	180	mJ	
$I_F$	Continuous Rectified Forward Current @ $T_C < 148\text{ }^\circ\text{C}$	30	A	
$I_{F, Max}$	Non-Repetitive Peak Forward Surge Current	$T_C = 25\text{ }^\circ\text{C}, 10\text{ }\mu\text{s}$	1125	A
		$T_C = 150\text{ }^\circ\text{C}, 10\text{ }\mu\text{s}$	1040	A
$I_{F, SM}$	Non-Repetitive Forward Surge Current	Half-Sine Pulse, $t_p = 8.3\text{ ms}$	150	A
$I_{F, RM}$	Repetitive Forward Surge Current	Half-Sine Pulse, $t_p = 8.3\text{ ms}$	75	A
$P_{tot}$	Power Dissipation	$T_C = 25\text{ }^\circ\text{C}$	240	W
		$T_C = 150\text{ }^\circ\text{C}$	40	W
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to +175	$^\circ\text{C}$	

### Thermal Characteristics

Symbol	Parameter	FFSP3065A	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.62	$^\circ\text{C/W}$

## Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFSP3065A	FFSP3065A	TO-220-2L	Tube	N/A	N/A	50 units

## Electrical Characteristics $T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted.

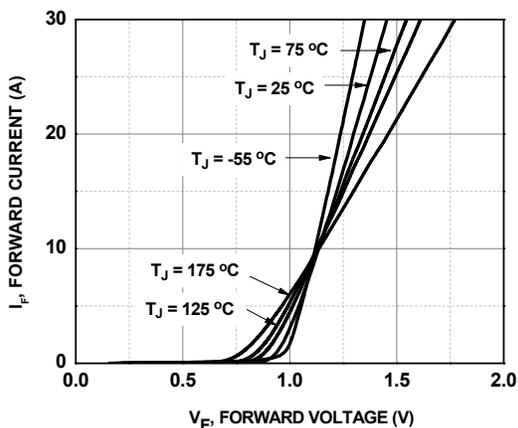
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_F$	Forward Voltage	$I_F = 30\text{ A}, T_C = 25\text{ }^\circ\text{C}$	-	1.50	1.75	V
		$I_F = 30\text{ A}, T_C = 125\text{ }^\circ\text{C}$	-	1.60	2.0	
		$I_F = 30\text{ A}, T_C = 175\text{ }^\circ\text{C}$	-	1.72	2.4	
$I_R$	Reverse Current	$V_R = 650\text{ V}, T_C = 25\text{ }^\circ\text{C}$	-	-	200	$\mu\text{A}$
		$V_R = 650\text{ V}, T_C = 125\text{ }^\circ\text{C}$	-	-	400	
		$V_R = 650\text{ V}, T_C = 175\text{ }^\circ\text{C}$	-	-	600	
$Q_C$	Total Capacitive Charge	$V = 400\text{ V}$	-	100	-	nC
C	Total Capacitance	$V_R = 1\text{ V}, f = 100\text{ kHz}$	-	1705	-	pF
		$V_R = 200\text{ V}, f = 100\text{ kHz}$	-	180	-	
		$V_R = 400\text{ V}, f = 100\text{ kHz}$	-	130	-	

**Notes:**

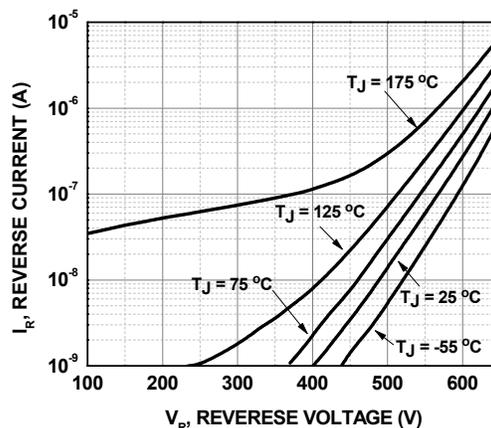
1: EAS of 180 mJ is based on starting  $T_J = 25\text{ }^\circ\text{C}$ ,  $L = 0.5\text{ mH}$ ,  $I_{AS} = 27\text{ A}$ ,  $V = 50\text{ V}$ .

## Typical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted.

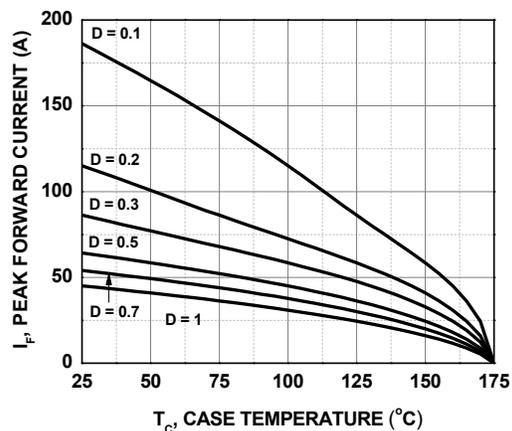
**Figure 1. Forward Characteristics**



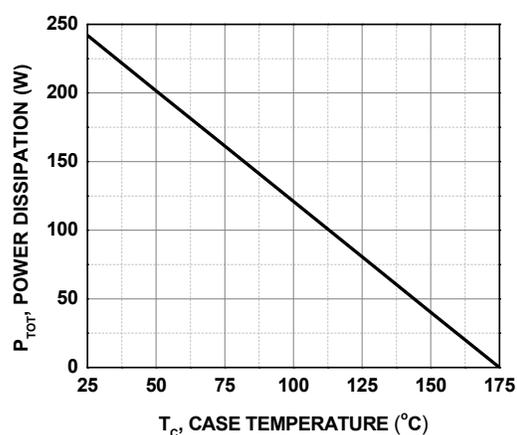
**Figure 2. Reverse Characteristics**



**Figure 3. Current Derating**

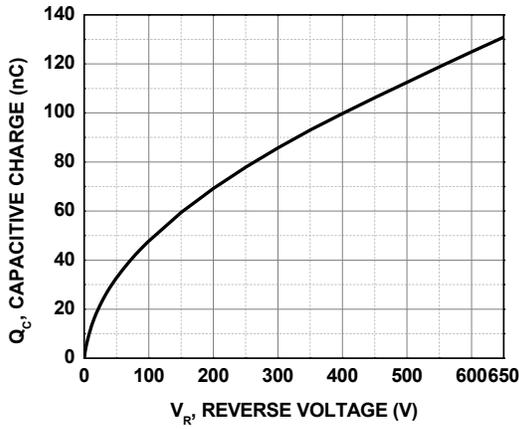


**Figure 4. Power Derating**

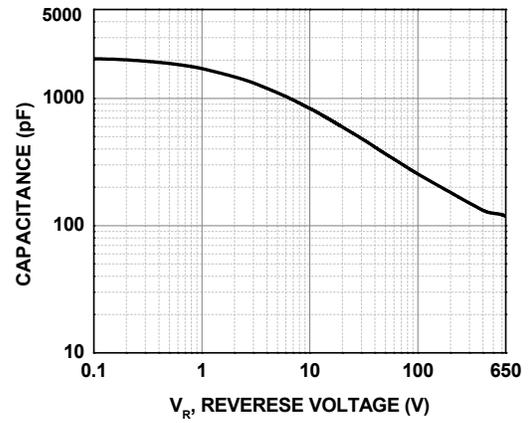


**Typical Characteristics**  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise noted.

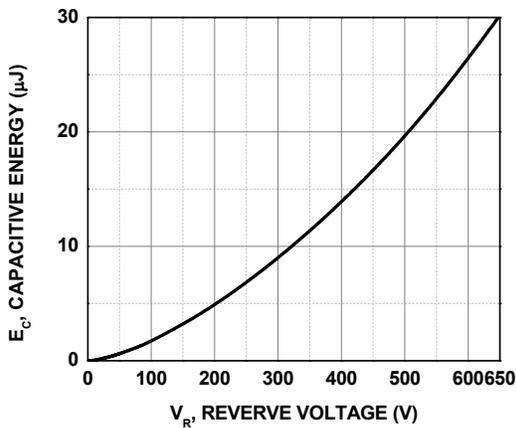
**Figure 5. Capacitive Charge vs. Reverse Voltage**



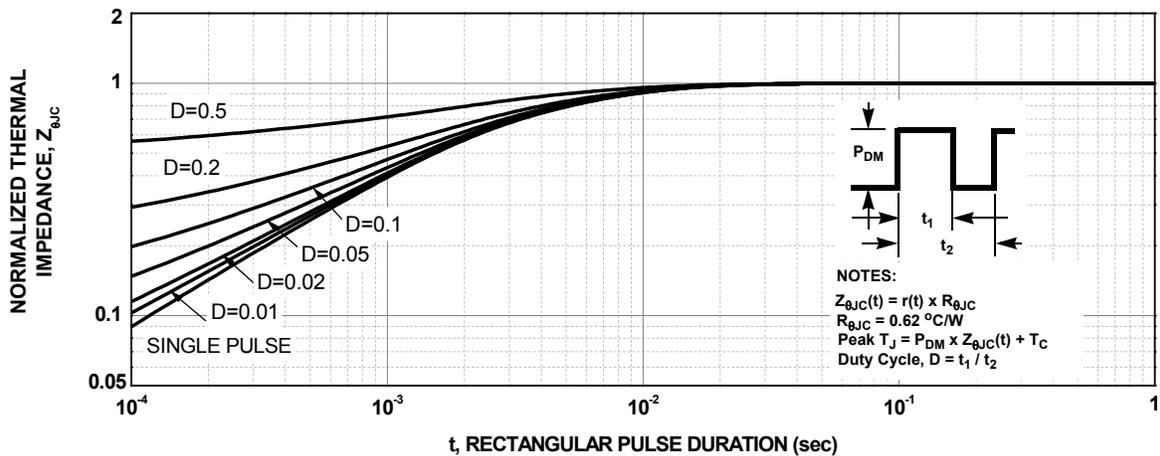
**Figure 6. Capacitance vs. Reverse Voltage**



**Figure 7. Capacitance Stored Energy**



**Figure 8. Junction-to-Case Transient Thermal Response Curve**



Test Circuit and Waveforms

Figure 9. Unclamped Inductive Switching Test Circuit & Waveform

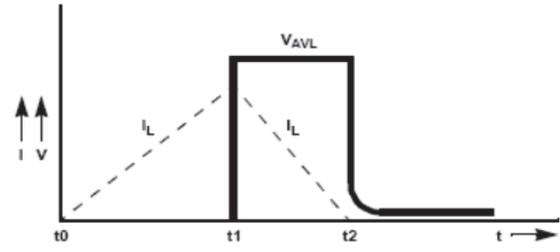
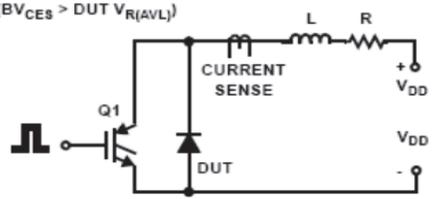
L = 0.5mH

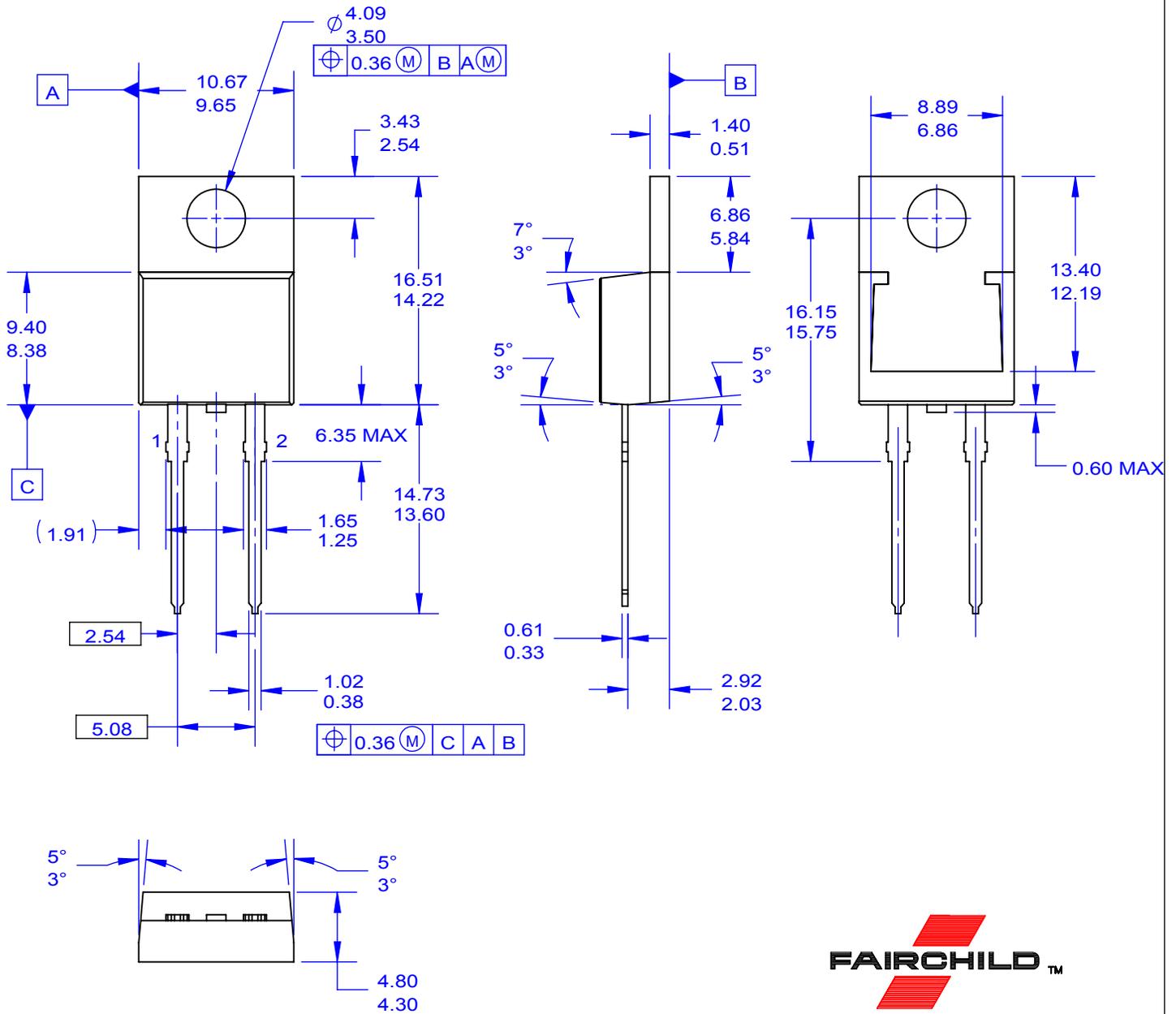
R < 0.1Ω

V<sub>DD</sub> = 50V

$$E_{AVL} = 1/2 L I^2 [V_{R(AVL)} / (V_{R(AVL)} - V_{DD})]$$

Q1 = IGBT (BV<sub>CES</sub> > DUT V<sub>R(AVL)</sub>)





NOTES:

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- C. DIMENSION AND TOLERANCE AS PER ASME Y14.5-2009.
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
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